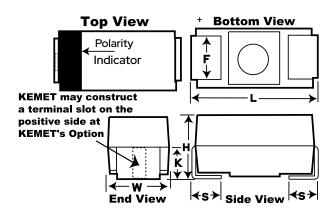


T498D226K020ZTE700

Obsolete

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 22 uF, 10%, 20 VDC, SMD, Molded, High Temperature, N/A, 700 mOhms, 7343, 3.1 mm, 1.3 mm



General Information	
Series	B45196P
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Specifications	
Capacitance	22 uF
Tolerance	10%
Voltage DC	20 VDC (85C), 15.94 VDC (125C), 13.4 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
ESR	0.7 Ohms (100kHz)
Ripple Current	462.9 mAmps (25C), 416.6 mAmps (85C), 185.2 mAmps (125C)
Leakage Current	4.4 uA

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	750

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